VS-HFA04TB60S-M3

Vishay Semiconductors

HEXFRED[®], Ultrafast Soft Recovery Diode, 4 A



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| PRIMARY CHARACTERISTICS | | | | | | |
|----------------------------------|-------------------------------|--|--|--|--|--|
| I _{F(AV)} | 4 A | | | | | |
| V _R | 600 V | | | | | |
| V _F at I _F | 1.4 V | | | | | |
| t _{rr} (typ.) | 17 ns | | | | | |
| T _J max. | 150 °C | | | | | |
| Package | D ² PAK (TO-263AB) | | | | | |
| Circuit configuration | Single | | | | | |

FEATURES

- Ultrafast recovery
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- Specified at operating temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION

VS-HFA04TB60S is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 4 A continuous current, the VS-HFA04TB60S is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (IRBM) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA04TB60S is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|--|-----------------------------------|-------------------------|-------------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | |
| Cathode to anode voltage | V _R | | 600 | V | | |
| Maximum continuous forward current | I _F | T _C = 100 °C | 4 | | | |
| Single pulse forward current | I _{FSM} | | 25 | А | | |
| Maximum repetitive forward current | I _{FRM} | | 16 | | | |
| Maximum power dissipation | PD | T _C = 25 °C | 25 | W | | |
| | | T _C = 100 °C | 10 | vv | | |
| Operating junction and storage temperature range | T _J , T _{Stg} | | -55 to +150 | °C | | |

Revision: 25-Oct-17

Document Number: 96215

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HALOGEN

FREE



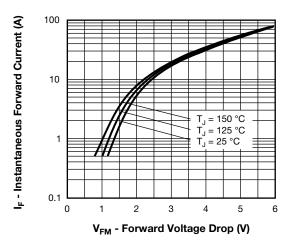
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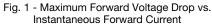
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| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | | |
|--|-----------------|--|------------|------|------|------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS | |
| Cathode to anode breakdown voltage | V _{BR} | I _R = 100 μA | | 600 | - | - | | |
| Maximum forward voltage | | I _F = 4.0 A | | - | 1.5 | 1.8 | V | |
| | V _{FM} | I _F = 8.0 A | See fig. 1 | - | 1.8 | 2.2 | v | |
| | | $I_F = 4.0 \text{ A}, T_J = 125 ^\circ\text{C}$ | | - | 1.4 | 1.7 | | |
| Maximum reverse leakage current | 1 | $V_{R} = V_{R}$ rated | See fig. 2 | - | 0.17 | 3.0 | | |
| Maximum reverse leakage current | I _{RM} | $T_J = 125 \text{ °C}, V_R = 0.8 \text{ x } V_R \text{ rated}$ | See lig. 2 | - | 44 | 300 | μA | |
| Junction capacitance | CT | V _R = 200 V | See fig. 3 | - | 4.0 | 8.0 | pF | |
| Series inductance | L _S | Measured lead to lead 5 mm from package body - 8 | | 8.0 | - | nH | | |

| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | | |
|---|---------------------------|---|--|------|------|------|-------|--|
| PARAMETER | SYMBOL | TEST CON | IDITIONS | MIN. | TYP. | MAX. | UNITS | |
| | t _{rr} | $I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}$ | õs, V _R = 30 V | - | 17 | - | | |
| Reverse recovery time See fig. 5, 6 | t _{rr1} | T _J = 25 °C | | - | 28 | 42 | ns | |
| 000 lig. 0, 0 | t _{rr2} | T _J = 125 °C | I _F = 4.0 A di _F /dt = 200 A/μs V _B = 200 V | - | 38 | 57 | | |
| Peak recovery current | I _{RRM1} | T _J = 25 °C | | - | 2.9 | 5.2 | A | |
| Peak recovery current | I _{RRM2} | T _J = 125 °C | | - | 3.7 | 6.7 | | |
| Reverse recovery charge | Q _{rr1} | T _J = 25 °C | | - | 40 | 60 | nC | |
| See fig. 7 | Q _{rr2} | T _J = 125 °C | | - | 70 | 105 | ne | |
| Peak rate of fall of recovery current during t_b , see fig. 8 | di _{(rec)M} /dt1 | T _J = 25 °C | | - | 280 | - | A/µs | |
| | di _{(rec)M} /dt2 | T _J = 125 °C | | - | 235 | - | γγµs | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | |
|---|-------------------|--|------------|------|-----|-------|--|--|
| PARAMETER SYMBOL TEST CONDITIONS MIN. TYP. MAX. UNITS | | | | | | | | |
| Lead temperature | Tlead | 0.063" from case (1.6 mm) for 10 s | - | - | 300 | °C | | |
| Thermal resistance, junction-to-case | R _{thJC} | | - | - | 5.0 | K/W | | |
| Thermal resistance, junction-to-ambient | R _{thJA} | Typical socket mount | - | - | 80 | r./vv | | |
| Wainht | | | - | 2.0 | - | g | | |
| Weight | | | - | 0.07 | - | oz. | | |
| Marking device | | Case style D ² PAK (TO-263AB) | HFA04TB60S | | | | | |





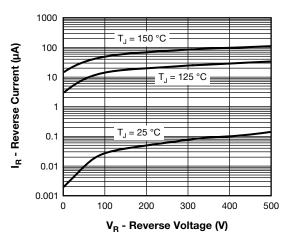


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

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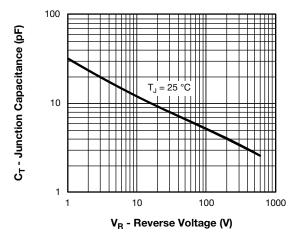


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

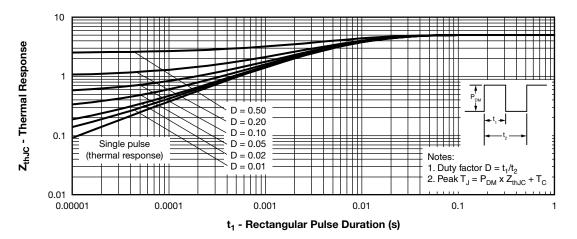


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

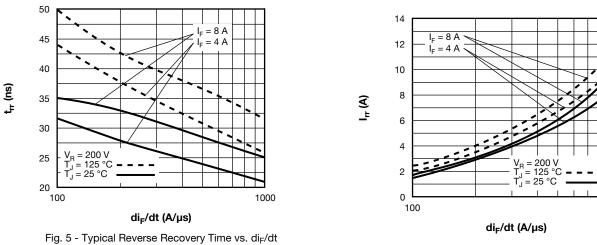


Fig. 6 - Typical Recovery Current vs. di_F/dt

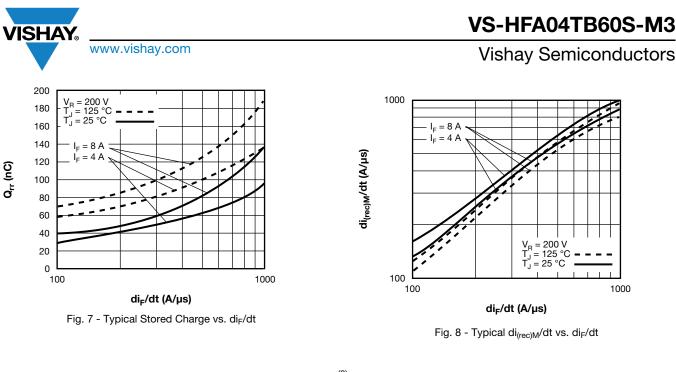
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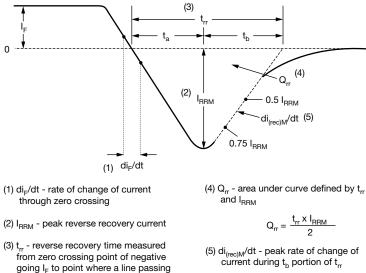


Fig. 9 - Reverse Recovery Waveform and Definitions

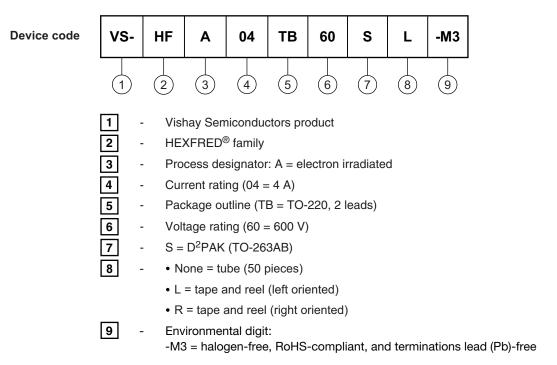
through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

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ORDERING INFORMATION TABLE



| ORDERING INFORMATION (Example) | | | | | | | | | |
|--------------------------------|---------------------------------------|------------------------|-------------------------|--|--|--|--|--|--|
| PREFERRED P/N | QUANTITY PER TUBE OR TAPE AND REEL | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | | | |
| VS-HFA04TB60S-M3 | 50 | 1000 | Antistatic plastic tube | | | | | | |
| VS-HFA04TB60SL-M3 | 800 | 800 | 13" diameter reel | | | | | | |
| VS-HFA04TB60SR-M3 | 800 | 800 | 13" diameter reel | | | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | | |
|----------------------------|--------------------------|--|--|--|--|--|
| Dimensions | www.vishay.com/doc?96164 | | | | | |
| Part marking information | www.vishay.com/doc?95444 | | | | | |
| Packaging information | www.vishay.com/doc?96424 | | | | | |

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D²PAK

DIMENSIONS in millimeters and inches



| ota | ted | 90 | °C |
|----------|------|-------------|----|
| <u>S</u> | cale | <u>ə:</u> 8 | :1 |

| SYMBOL | MILLIM | MILLIMETERS | | INCHES | | |
|--------|--------|-------------|-------|--------|-------|--|
| STMBOL | MIN. | MAX. | MIN. | MAX. | NOTES | |
| Α | 4.06 | 4.83 | 0.160 | 0.190 | | |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | | |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | |
| с | 0.38 | 0.74 | 0.015 | 0.029 | | |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | |

| SYMBOL | MILLIM | ETERS | INCHES | | NOTES |
|--------|----------|-------|--------|-------|-------|
| STNDUL | MIN. | MAX. | MIN. | MAX. | NOTES |
| D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| е | 2.54 BSC | | 0.100 | BSC | |
| Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| L | 1.78 | 2.79 | 0.070 | 0.110 | |
| L1 | - | 1.65 | - | 0.066 | 3 |
| L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| L3 | 0.25 BSC | | 0.010 | BSC | |
| L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 13-Jul-17

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Document Number: 96164

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